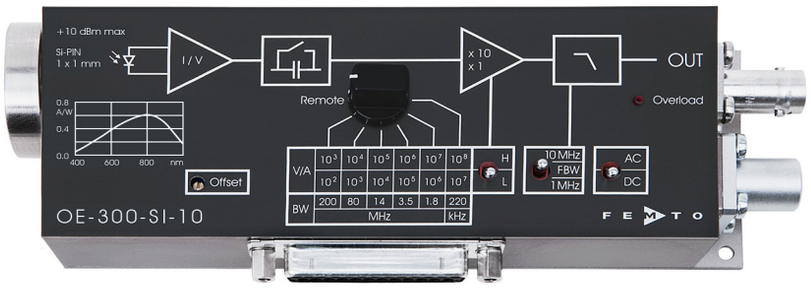
Datasheet OE-300-SI-10

200 MHz Variable Gain Photoreceiver



The image shows model OE-300-SI-10-FST with 1.035"-40 threaded flange and coupler ring.

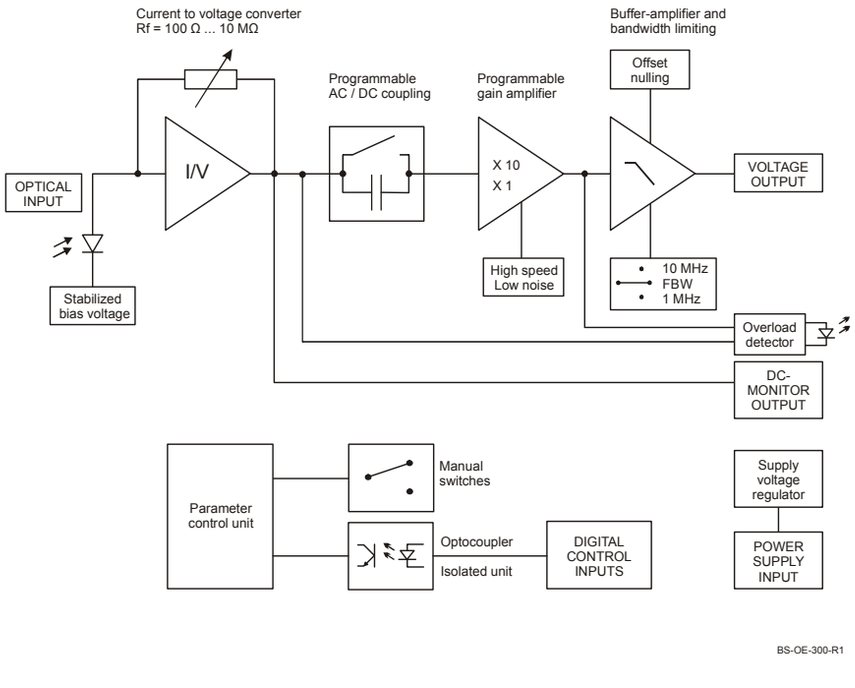
Features

- **Adjustable transimpedance gain from 10^2 to 10^8 V/A**
- **Wide bandwidth up to 200 MHz**
- **Si-PIN photodiode covering the 400 to 1000 nm wavelength range**
- **Large optical detector size 1 x 1 mm**
- **High dynamic input range up to 10 mW optical power**
- **Very low noise, NEP down to 76 fW/vHz**
- **Switchable low pass filters for minimizing wideband noise**
- **Threaded 1.035"-40 and unthreaded 25 mm dia. free space input available, compatible with many optical standard accessories**
- **1.035"-40 input easily convertible to fiber optic input with optional adapter**
- **Full manual and remote control capability**

Applications

- **All-purpose low-noise photoreceiver (O/E converter) for the MHz range**
- **Time resolved optical pulse and power measurements**
- **Laser intensity noise measurements (RIN)**
- **Optical front-end for oscilloscopes, spectrum analyzers, A/D converters and RF lock-in amplifiers**

Block Diagram



200 MHz Variable Gain Photoreceiver

Available Versions

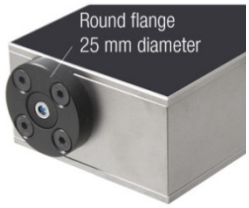
OE-300-SI-10-FST

Internal threaded coupler ring with 30 mm outer diameter (included)

1.035"-40 threaded flange for free space applications compatible with many optical standard accessories and for use with various types of fiber connector adapters.

Optional: Fiber adapters PRA-FC and PRA-FSMA

OE-300-SI-10-FS



25 mm dia. unthreaded flange for free space applications compatible with many optical standard accessories.

Related OE-300 Models

See separate datasheets for following models on www.femto.de:

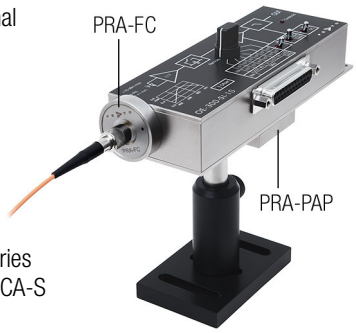
OE-300-SI-30-FST	Si-PIN, ø 3 mm, 320 - 1000 nm 1.035"-40 threaded flange
OE-300-SI-30-FS	Si-PIN, ø 3 mm, 320 - 1000 nm 25 mm dia. unthreaded flange
OE-300-IN-01-FC	InGaAs-PIN, ø 80 µm, 900 - 1700 nm FC fiber receptacle only
OE-300-IN-03-FST	InGaAs-PIN, ø 300 µm, 800 - 1700 nm 1.035"-40 threaded flange
OE-300-IN-03-FS	InGaAs-PIN, ø 300 µm, 800 - 1700 nm 25 mm dia. unthreaded flange
OE-300-S	customized versions available on request

200 MHz Variable Gain Photoreceiver

Available Accessories

PRA-FSMA
PRA-FC

fiber-adapter with external 1.035"-40 thread



PRA-PAP

post adapter plate,
easy to mount on
FEMTO photoreceiver series
OE, FWPR, HCA-S and LCA-S

PS-15

power supply,
input: 100 - 240 VAC,
output: ±15 VDC, +400/–250 mA

LUCI-10

compact digital I/O interface for USB remote control,
supports opto-isolation of amplifier signal path from PC
USB port, 16 digital outputs, 3 opto-isolated digital inputs,
bus-powered operation

Specifications

	Test conditions	$V_S = \pm 15$ V, $T_A = 25$ °C, system impedance = 50 Ω
Gain	Transimpedance gain	1 x 10^2 ... 1 x 10^8 V/A
	Gain accuracy	±1 %
Frequency Response	Lower cut-off frequency	DC/100 Hz, switchable
	Upper cut-off frequency	up to 200 MHz (see table below), switchable to 1 MHz or 10 MHz
Input	Noise equivalent power (NEP)	see table below
	Max. CW saturation power	see table below
Detector	Detector	Si-PIN photodiode
	Active area	1 mm x 1 mm (1 mm^2)
	Spectral response	400 - 1000 nm
	Sensitivity R	0.58 A/W typ. @ 850 nm
	Dark current	0.12 nA typ.

200 MHz Variable Gain Photoreceiver

Specifications (continued)

Performance Depending on Gain Setting

Gain setting (low noise) (V/A)	10^2	10^3	10^4	10^5	10^6	10^7
Upper cut-off frequency (–3 dB)	200 MHz	80 MHz	14 MHz	3.5 MHz	1.8 MHz	220 kHz
NEP (/√Hz, @ 850 nm)	322 pW	25 pW	2.9 pW	740 fW	260 fW	78 fW
Measured at	20 MHz	8 MHz	1.4 MHz	350 kHz	180 kHz	22 kHz
Integrated input noise (RMS)*	7.5 µW	580 nW	35 nW	4.9 nW	1.3 nW	100 pW
CW sat. power (@ 850 nm)	10 mW	1.7 mW	170 µW	17 µW	1.7 µW	170 nW

Gain setting (high speed) (V/A)	10^3	10^4	10^5	10^6	10^7	10^8
Upper cut-off frequency (–3 dB)	175 MHz	80 MHz	14 MHz	3.5 MHz	1.8 MHz	220 kHz
NEP (/√Hz, @ 850 nm)	231 pW	10 pW	2.2 pW	670 fW	228 fW	76 fW
Measured at	18 MHz	8 MHz	1.4 MHz	350 kHz	180 kHz	22 kHz
Integrated input noise (RMS)*	4.5 µW	440 nW	31 nW	4.8 nW	1.3 nW	100 pW
CW sat. power (@ 850 nm)	1.7 mW	170 µW	17 µW	1.7 µW	170 nW	17 nW

* The integrated input noise is measured with a shaded input in the full bandwidth (“FBW”) setting (referred to 850 nm). The measurement bandwidth is 3 x the upper cut-off frequency at the specific gain setting; filter slope is a 1st order roll-off.

The input referred peak-peak noise can be calculated from the RMS noise as follows:

$$P_{\text{Input noise peak-to-peak}} = P_{\text{Input noise RMS}} \times 6$$

The output noise is given by:

$$U_{\text{Output noise RMS}} = P_{\text{Input noise RMS}} \times \text{gain} \times R$$

$$U_{\text{Output noise peak-to-peak}} = U_{\text{Output noise RMS}} \times 6 = P_{\text{Input noise RMS}} \times \text{gain} \times R \times 6$$

The integrated noise will be reduced considerably by setting the low pass filter to “1 MHz” or “10 MHz” instead of “FBW”. This is especially useful for continuous wave (CW) measurements.

Output

Output voltage range	±1 V (@ 50 Ω load), for linear amplification
Output impedance	50 Ω (designed for 50 Ω load)
Slew rate	1000 V/µs
Max. output current	±40 mA
Output offset compensation	adjustable by offset potentiometer and external control voltage, output offset compensation range min. ±100 mV

Ext. Offset Control

Control voltage range	±10 V
Offset control input impedance	15 kΩ

Indicator LED

Function	overload

Digital Control

Control input voltage range	LOW bit: –0.8 ... +1.2 V, HIGH bit: +2.3 ... +12 V
Control input current	0 mA @ 0 V, 1.5 mA @ +5 V, 4.5 mA @ +12 V
Overload output	non active: <0.4 V @ 0 ... –1 mA active: typ. 5 ... 5.1 V @ 0 ... 2 mA

Power Supply

Supply voltage	±15 V
Supply current	+110/–90 mA (depends on operating conditions, recommended power supply capability min ±200 mA)
Stabilized power supply output	±12 V, max. 20 mA, +5 V, max. 150 mA

Case

Weight	320 g (0.74 lb.)
Material	AlMg4.5Mn, nickel-plated

200 MHz Variable Gain Photoreceiver

Specifications (continued)

Input Flange

Material: 1.4305 stainless steel, glass bead blasted
(1.035"-40 threaded flange)
AlMg4.5Mn, nickel-plated
(25 mm dia. unthreaded flange)

Coupler Ring

Material: 1.4305 stainless steel, glass bead blasted

DC Monitor Output

Monitor output gain:

Mode	Monitor gain
Low noise	Gain setting divided by –1
High speed	Gain setting divided by –10

Monitor output polarity	inverting
Monitor output voltage range	±1 V (@ ≥1 MΩ load)
Monitor output bandwidth	DC ... 1 kHz
Monitor output impedance	1 kΩ (designed for ≥1 MΩ load)

Temperature Range

Storage temperature	–40 ... +80 °C
Operating temperature	0 ... +60 °C

Absolute Maximum Ratings

Max. CW power (averaged)	12 mW
Digital control input voltage	–5 V/+16 V relative to digital ground DGND (pin 9)
Analog control input voltage	±15 V relative to analog ground AGND (pin 3)
Power supply voltage	±20 V

Connectors

Input

OE-300-SI-10-FST	1.035"-40 threaded flange for free space applications and for use with various types of fiber connector adapters
OE-300-SI-10-FS	25 mm unthreaded round flange for free space applications

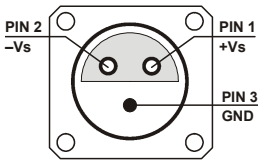
Output

BNC jack (female)

Power supply

Lemo® series 1S, 3-pin fixed socket
(mating plug type: FFA.1S.303.CLAC52)

Pin 1: +15 V
Pin 2: –15 V
Pin 3: GND



Control port

Sub-D 25-pin, female, qual. class 2

Pin 1:	+12 V (stabilized power supply output)
Pin 2:	–12 V (stabilized power supply output)
Pin 3:	AGND (analog ground for pins 1 - 8)
Pin 4:	+5 V (stabilized power supply output)
Pin 5:	digital output: overload (referred to pin 3)
Pin 6:	DC Monitor output
Pin 7:	NC (= not connected)
Pin 8:	output offset control voltage input
Pin 9:	DGND (ground for digital control pins 10 - 16)
Pin 10:	digital control input: gain, LSB
Pin 11:	digital control input: gain
Pin 12:	digital control input: gain, MSB
Pin 13:	digital control input: AC/DC
Pin 14:	digital control input: high speed / low noise
Pin 15:	upper cut-off frequency limit 10 MHz
Pin 16:	upper cut-off frequency limit 1 MHz
Pin 17 - 25:	NC (= not connected)

200 MHz Variable Gain Photoreceiver

Scope of Delivery

OE-300-SI-10, threaded coupler ring ("FST" version only), Lemo® 3-pin connector, datasheet, transport package

Remote Control Operation

General

Remote control input bits are opto-isolated and connected by a logical OR function to the local switch settings. For remote control set the corresponding local switches to "Remote", "DC", "L" (low noise mode) and "FBW", and select the desired setting via a bit code at the corresponding digital inputs.
Mixed operation, e.g. local AC/DC setting and remote controlled gain setting, is also possible.

Gain setting

Low noise Gain (V/A) Pin 14=LOW	High speed Gain (V/A) Pin 14=HIGH	Pin 12 MSB	Pin 11	Pin 10 LSB
10^2	10^3	LOW	LOW	LOW
10^3	10^4	LOW	LOW	HIGH
10^4	10^5	LOW	HIGH	LOW
10^5	10^6	LOW	HIGH	HIGH
10^6	10^7	HIGH	LOW	LOW
10^7	10^8	HIGH	LOW	HIGH

AC/DC setting

Coupling	Pin 13
DC	LOW
AC	HIGH

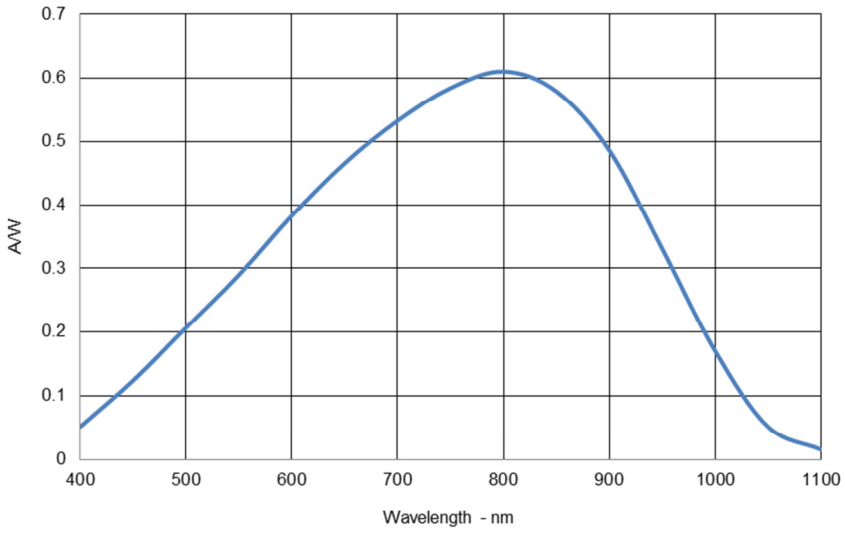
Low pass filter setting

Upper cut-off freq. limit	Pin 15	Pin 16
full bandwidth	LOW	LOW
10 MHz	HIGH	LOW
1 MHz	LOW	HIGH

High speed / low noise setting

Mode	Pin 14
low noise mode	LOW
high speed mode	HIGH

Spectral Responsivity



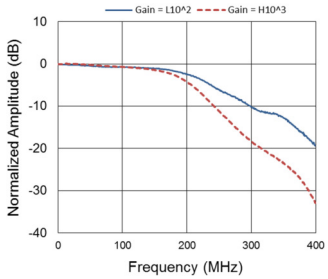
200 MHz Variable Gain Photoreceiver

Typical Performance Characteristic

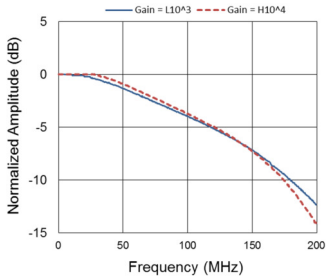
Frequency response

$V_{Supply} = \pm 15\ V_{DC}$; $R_{Load} = 50\ \Omega$

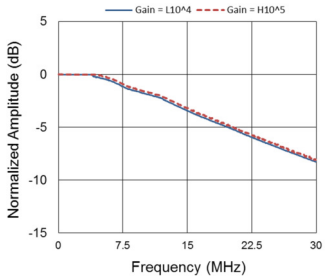
Gain setting: $L10^2$, $H10^3$



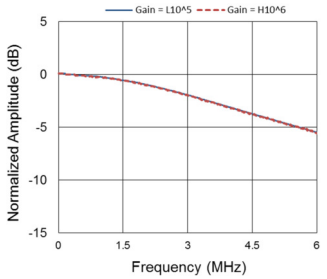
Gain setting: $L10^3$, $H10^4$



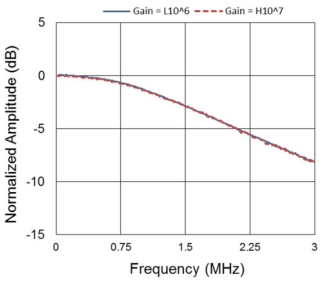
Gain setting: $L10^4$, $H10^5$



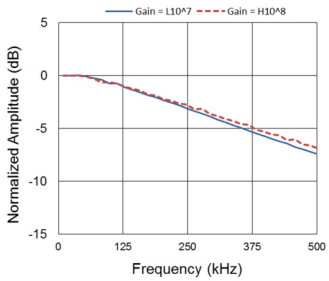
Gain setting: $L10^5$, $H10^6$



Gain setting: $L10^6$, $H10^7$



Gain setting: $L10^7$, $H10^8$

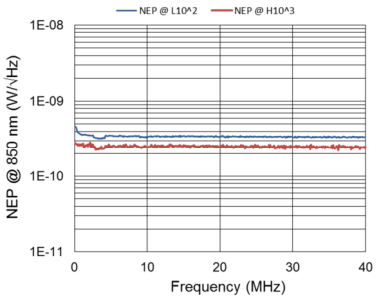


200 MHz Variable Gain Photoreceiver

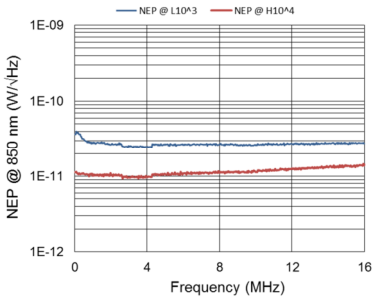
Typical Performance Characteristic (continued)

Input noise equivalent power (NEP)

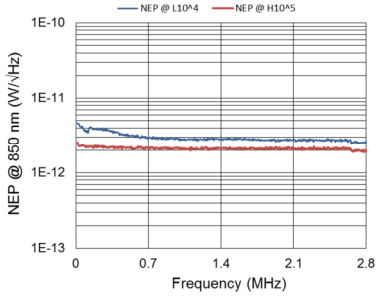
Gain setting $L10^2$, $H10^3$



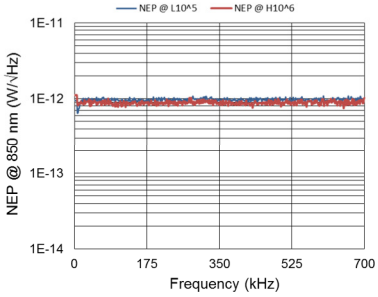
Gain setting $L10^3$, $H10^4$



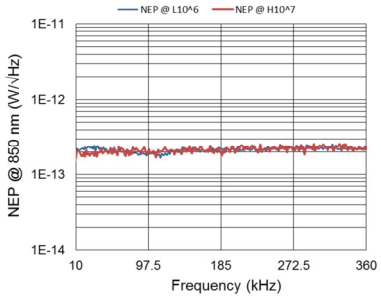
Gain setting: $L10^4$, $H10^5$



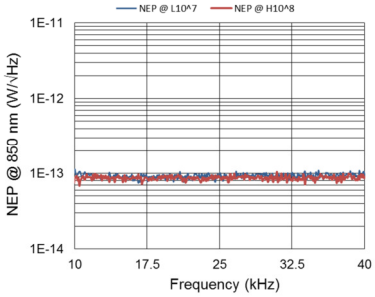
Gain setting: $L10^5$, $H10^6$



Gain setting: $L10^6$, $H10^7$



Gain setting: $L10^7$, $H10^8$

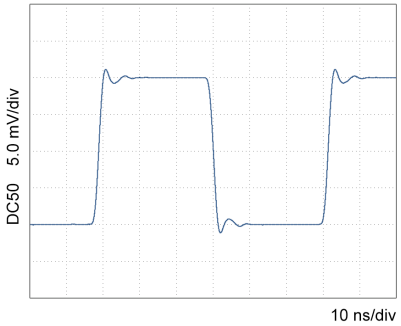


200 MHz Variable Gain Photoreceiver

Typical Performance Characteristic (continued)

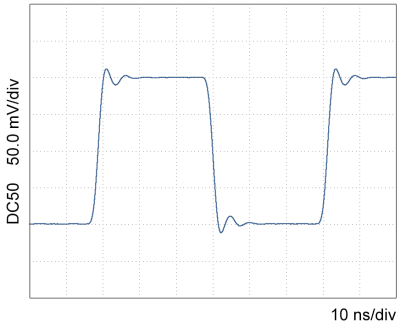
Signal pulse response

Gain setting L10[2]



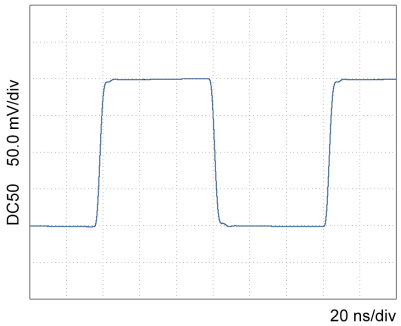
Rise: 1.85 ns Fall: 1.89 ns

Gain setting H10[3]



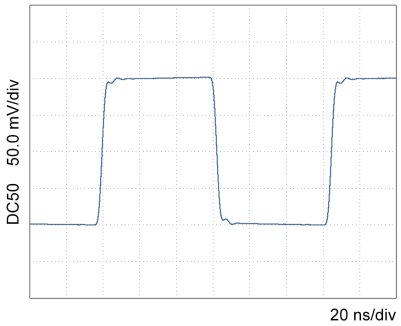
Rise: 2.23 ns Fall: 2.27 ns

Gain setting L10[3]



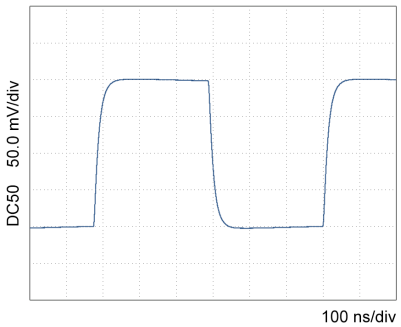
Rise: 3.20 ns Fall: 3.23 ns

Gain setting H10[4]



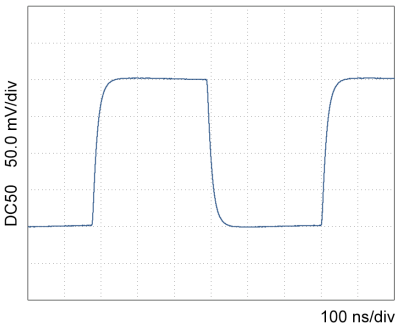
Rise: 3.44 ns Fall: 3.47 ns

Gain setting L10[4]



Rise: 26.87 ns Fall: 25.66 ns

Gain setting H10[5]

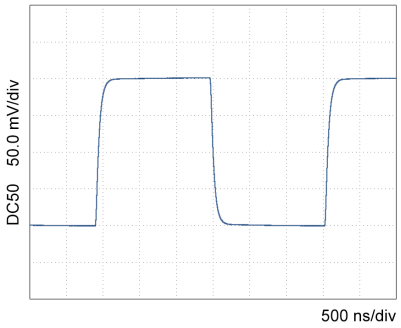


Rise: 27.02 ns Fall: 26.10 ns

200 MHz Variable Gain Photoreceiver

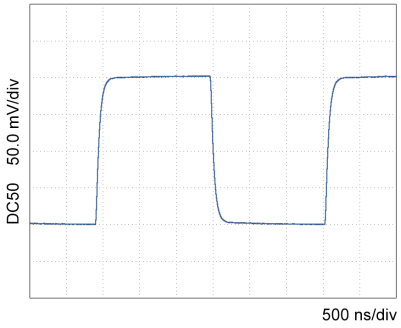
Typical Performance Characteristic (continued)

Gain setting L10[5]



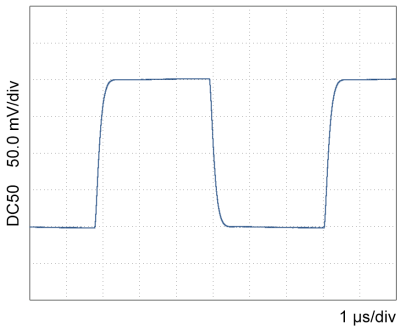
Rise: 91.80 ns Fall: 91.88 ns

Gain setting H10[6]



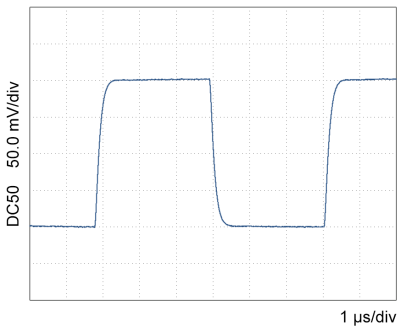
Rise: 94.44 ns Fall: 93.16 ns

Gain setting L10[6]



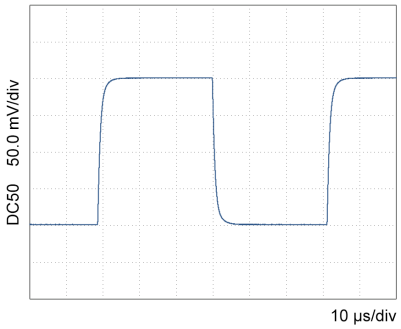
Rise: 233.36 ns Fall: 238.40 ns

Gain setting H10[7]



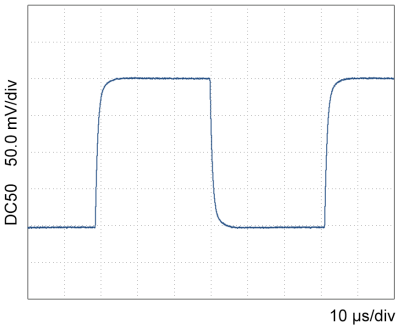
Rise: 231.92 ns Fall: 234.40 ns

Gain setting L10[7]



Rise: 1606.4 ns Fall: 1584.8 ns

Gain setting H10[8]



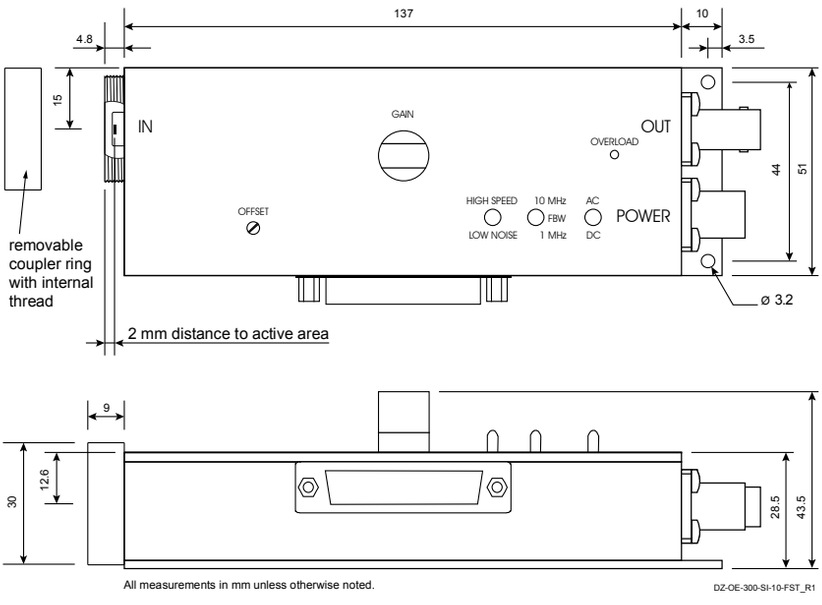
Rise: 1621.6 ns Fall: 1608.8 ns

Datasheet OE-300-SI-10

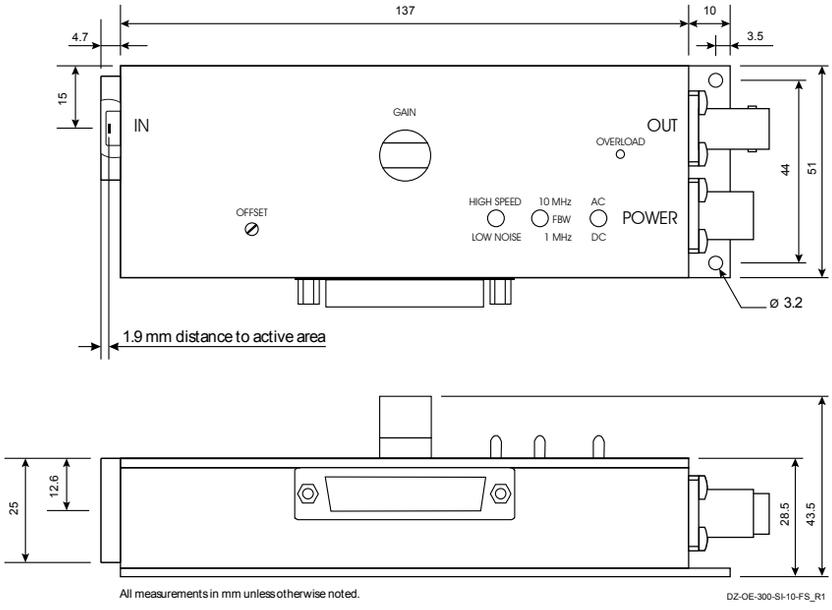
200 MHz Variable Gain Photoreceiver

Dimensions

Threaded free space input OE-300-SI-10-FST:



Free space input OE-300-SI-10-FS:



FEMTO Messtechnik GmbH
Klosterstr. 64
10179 Berlin · Germany
Phone: +49 30 280 4711-0
Fax: +49 30 280 4711-11
Email: info@femto.de
www.femto.de